

BAS70-00-V to BAS70-06-V

Vishay Semiconductors

Small Signal Schottky Diodes, Single & Dual

Features

- These diodes feature very low turn-on voltage and fast switching
- These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Mechanical Data

Case: SOT-23

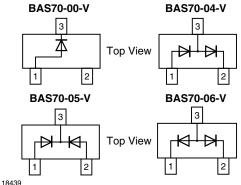
Weight: approx. 8.8 mg

Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS08 / 3 k per 7" reel (8 mm tape), 15 k/box

Parts Table





Part	Ordering code	Type Marking	Remarks
BAS70-00-V	BAS70-00-V-GS18 or BAS70-00-V-GS08	73	Tape and Reel
BAS70-04-V	BAS70-04-V-GS18 or BAS70-04-V-GS08	74	Tape and Reel
BAS70-05-V	BAS70-05-V-GS18 or BAS70-05-V-GS08	75	Tape and Reel
BAS70-06-V	BAS70-06-V-GS18 or BAS70-06-V-GS08	76	Tape and Reel

eЗ

RoHS

COMPLIANT

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		$V_{RRM} = V_{RWM} = V_{R}$	70	V
Forward continuous current		١ _F	200 ¹⁾	mA
Surge forward current	t _p < 1 s	I _{FSM}	600 ¹⁾	mA
Power dissipation ¹⁾		P _{tot}	200 ¹⁾	mW

¹⁾ Device on fiberglass substrate, see layout on next page

Thermal Characteristics

 $T_{amb} = 25 \text{ °C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		R _{thJA}	500 ¹⁾	K/W
Junction temperature		Тj	125	°C
Storage temperature range		T _{stg}	- 65 to + 150	°C

¹⁾ Device on fiberglass substrate, see layout on next page

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Electrical Characteristics

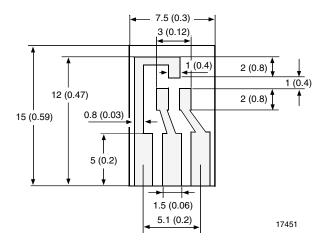
T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Reverse breakdown voltage	$I_{R} = 10 \ \mu A \ (pulsed)$	V _(BR)	70			V
Leakage current	V _R = 50 V	I _R		20	100	nA
Forward voltage	I _F = 1.0 mA	V _F			410	mV
Forward voltage ¹⁾	I _F = 15 mA,	V _F			1000	mV
Diode capacitance	V _R = 0 V, f = 1 MHz	CD		1.5	2	pF
Reverse recovery time	$I_F = I_R = 10 \text{ mA}, \text{i}_R = 1 \text{ mA},$ $R_L = 100 \Omega$	t _{rr}			5	ns

^1) Pulse test; $t_p \leq 300 \ \mu s$

Layout for R_{thJA} test

Thickness: Fiberglass 1.5 mm (0.059 in.) Copper leads 0.3 mm (0.012 in.)

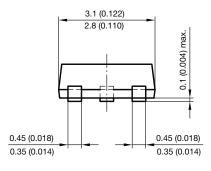


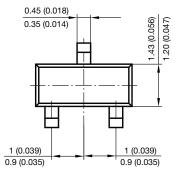


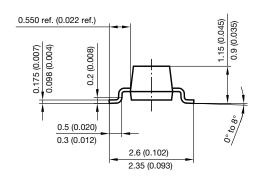
BAS70-00-V to BAS70-06-V

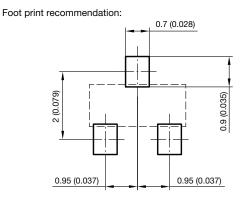
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Package Dimensions in millimeters (inches): SOT-23









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